Session Program

25–28 Jun 2006

8th RD50 Workshop

Defect and Material Characterization

Prague

Monday 26 June

09:20

Defect and Material Characterization

Session | **Location:** Prague

09:20–09:40 **Defect kinetics in Epi/Cz silicon after Co60-gamma irradiation**

Speaker
Ioana Pintilie

09:40–10:00
Characterization of irradiated silicon structures by microwave absorption techniques

Speaker
Eugenijus Gaubas

10:00–10:30 **Coffee break**

10:30–10:50
DLTS measurements of Epitaxial and MCZ silicon detectors after 26 MeV proton irradiation

Speaker
Frank Hoeniger

10:50–11:20 **Discussion on Defect and Material Characterization**

11:20